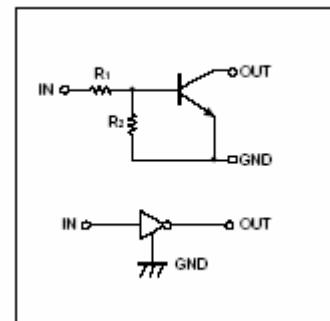


## Features

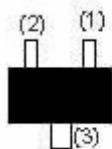
1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors(see equivalent circuit).
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input.They also have the advantage of almost completely eliminating parasitic effects.
3. Only the on/off conditions need to be set for operation, making device design easy.

●Equivalent circuit



## PIN CONNECTIONS AND MARKING

**DTC114EE**

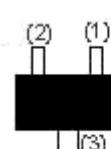


1.IN  
2.GND  
3.OUT

SOT-523

Addreviated symbol: 24

**DTC114EUA**

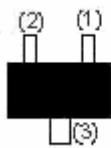


1.IN  
2.GND  
3.OUT

SOT-323

Addreviated symbol: 24

**DTC114EKA**

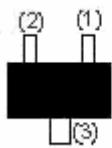


1.IN  
2.GND  
3.OUT

SOT-23-3L

Addreviated symbol: 24

**DTC114ECA**

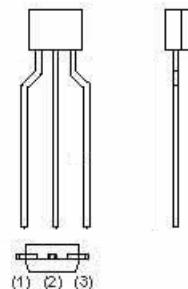


1.IN  
2.GND  
3.OUT

SOT-23

Addreviated symbol: 24

**DTC114ESA**



1.GND  
2.OUT  
3.IN

TO-92S

Absolute maximum ratings( $T_a=25^\circ\text{C}$ )

Parameter	Symbol	Limits (DTC114E□)					Unit
		E	UA	CA	KA	SA	
Supply voltage	$V_{CC}$	50					V
Input voltage	$V_{IN}$	-10~40					V
Output current	$I_O$	50					mA
	$I_{C(MAX)}$	100					
Power dissipation	$P_d$	150		200		300	mW
Junction temperature	$T_j$	150					°C
Storage temperature	$T_{STG}$	-55~150					°C

Electrical characteristics ( $T_a=25^\circ\text{C}$ )

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$			0.5	V	$V_{CC}=5\text{V}, I_O=100\mu\text{A}$
	$V_{I(on)}$	3				$V_O=0.3\text{V}, I_O=10\text{ mA}$
Output voltage	$V_O(on)$			0.3	V	$I_O/I_I=10\text{mA}/0.5\text{mA}$
Input current	$I_I$			0.88	mA	$V_I=5\text{V}$
Output current	$I_O(off)$			0.5	μA	$V_{CC}=50\text{V}, V_I=0$
DC current gain	$G_I$	30				$V_O=5\text{V}, I_O=5\text{mA}$
Input resistance	$R_I$	7	10	13	KΩ	
Resistance ratio	$R_2/R_1$	0.8	1	1.2		
Transition frequency	$f_T$		250		MHz	$V_O=10\text{V}, I_O=5\text{mA}, f=100\text{MHz}$

## Typical Characteristics

### ● Electrical characteristic curves

